ICTE5.0 THRU ICTE15C SERIES

TRANSZORB[™] TRANSIENT VOLTAGE SUPPRESSOR Stand-off Voltage - 5.0 to 15 Volts Peak Pulse Power - 1500 Watts

FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Glass passivated junction
- 1500W Peak pulse power capability with a
- 10/1000µs waveform, repetition rate (duty cycle): 0.05%
- Excellent clamping capability
- Low incremental surge resistance
- Fast response time: typically less than 1.0ps from 0 Volts to V_(BR) for uni-directional and 5.0ns for bi-directional
- Ideal for data and bus line applications
- High temperature soldering guaranteed: 265°C/10 seconds, 0.375" (9.5mm) lead length, 5lbs. (2.3 kg) tension
- Includes 1N6373 thru 1N6385

MECHANICAL DATA

Case: Molded plastic over a passivated junction **Terminals:** Plated Axial leads, solderable per MIL-STD-750, Method 2026

Polarity: For uni-directional types the color band denotes the cathode, which is posititive with respect to the anode under normal TVS operation

Mounting Position: Any Weight: 0.045 ounce, 1.2 grams

MAXIMUM RATINGS AND CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

WWWW.	SYMBOL	VALUE	UNITS
Peak <mark>pulse power dissip</mark> ation with a 10/100 <mark>0μs wave</mark> form (NOTE 1, FIG. 1)	Рррм	Minimum 1500	Watts
Steady state power dissipation, TL= 75°C at lead lengths 0.375" (9.5mm)	Pm(AV)	6.5	Watts
Peak pulse current with a 10/1000µs waveform (NOTE 1, FIG. 3)	Іррм	SEE TABLE 1 & 2	Amps
Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load for uni-directional only (JEDEC Method) (NOTE 2)	IFSM	200	Amps
Maximum instantaneous forward voltage at 100A for uni-directional only	VF	3.5	Volts
Operating junction and storage temperature range	TJ, TSTG	-55 to +175	°C

NOTES

(1) Non-repetitive current pulse, per Fig. 3 and derated above T_A= 25°C per Fig. 2 (2) 8.3ms single half sine-wave, duty cycle=4 pulses per minute maximum







ELECTRICAL CHARACTERISTICS at 25°C (JEDEC REGISTERED DATA) TABLE 1

JEDEC TYPE NUMBER	GENERAL SEMICONDUCTOR PART NUMBER	STAND-OFF VOLTAGE Vwm (VOLTS)	MINIMUM ⁽³⁾ BREAKDOWN VOLTAGE at 1.0mA. V _(BR) (VOLTS)	MAXIMUM REVERSE LEAKAGE at Vwm Ισ (μΑ)	MAXIMUM CLAMPING VOLTAGE at IPP = 1.0A Vc (VOLTS)	MAXIMUM CLAMPING VOLTAGE at IPP = 10A Vc (VOLTS)	MAXIMUM PEAK PULSE CURRENT IPP (Amps)
1N6373 ⁽²⁾	ICTE-5 ⁽²⁾	5.0	6.0	300	7.1	7.5	160
1N6374	ICTE-8	8.0	9.4	25.0	11.3	11.5	100
1N6375	ICTE-10	10.0	11.7	2.0	13.7	14.1	90
1N6376	ICTE-12	12.0	14.1	2.0	16.1	16.5	70
1N6377	ICTE-15	15.0	17.6	2.0	20.1	20.6	60

ELECTRICAL CHARACTERISTICS AT 25°C (JEDEC REGISTERED DATA) TABLE 2

JEDEC TYPE NUMBER	GENERAL SEMICONDUCTOR PART NUMBER	STAND-OFF VOLTAGE Vwm (VOLTS)	MINIMUM ⁽³⁾ BREAKDOWN VOLTAGE at 1.0mA. V _(BR) (VOLTS)	MAXIMUM REVERSE LEAKAGE at Vwm Ισ (μΑ)	MAXIMUM CLAMPING VOLTAGE at IPP = 1A Vc (VOLTS)	MAXIMUM CLAMPING VOLTAGE at IPP = 10A Vc (VOLTS)	MAXIMUM PEAK PULSE CURRENT IPP (Amps)
1N6382	ICTE-8C	8.0	9.4	50.0	11.4	11.6	100
1N6383	ICTE-10C	10.0	11.7	2.0	14.1	14.5	90
1N6384	ICTE-12C	12.0	14.1	2.0	16.7	17.1	70
1N6385	ICTE-15C	15.0	17.6	2.0	20.8	21.4	60

NOTES:

(1) "C " Suffix indicates bi-directional
(2) ICTE-5 and 1N6373 are not available as bi-directional

(3) The minimum breakdown voltage as shown takes into consideration the ±1 Volt tolerance normally specified for power supply regulation on most integrated circuit manufacturers data sheets. Please consult factory for devices that require reduced clamping voltages where tighter regulated power supply voltages are employed. (4) Clamping Factor: 1.33 at full lo rated power; 1.20 at 50% rated power; Clamping Factor: the ratio of the actual Vc (Clamping Voltage) to the V_(BR) (Breakdown Voltage) as measured on a specific device.



RATINGS AND CHARACTERISTIC CURVES ICTE5.0 THRU ICTE15C SERIES













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FIG. 7 - TYPICAL CHARACTERISTIC CLAMPING VOLTAGE



